United States Patent [19]

Ooshio et al.

[54] ELECTROSTATIC CHUCK

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- [22] Filed: Jul. 30, 1985

[30] Foreign Application Priority Data

Jul. 31, 1984 [JP] Japan 59-117493

- [51] Int. Cl.⁴ B25B 11/00
- [52] U.S. Cl. 279/1 M; 269/8;
- 269/13; 361/145; 361/234

 [58] Field of Search
 361/145; 234;

 29/DIG. 95; 269/8, 13; 279/1 M, 1 R

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[11] Patent Number: 4,645,218

[45] Date of Patent: Feb. 24, 1987

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Primary Examiner-Gil Weidenfeld

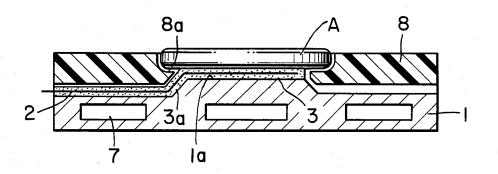
Assistant Examiner-Steven C. Bishop

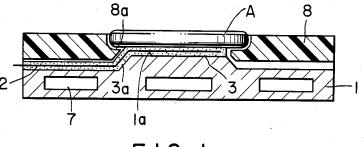
Attorney, Agent, or Firm—Schwartz, Jeffery, Schwaab, Mack, Blumenthal & Evans

[57] ABSTRACT

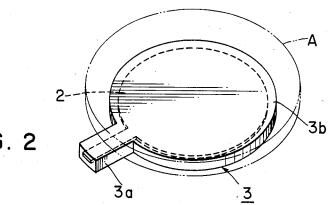
An electrostatic chuck for holding a work by electrostatic forces, which has an electrostatic attraction body for attracting the work, an electrostatic conductive support body for supporting the electrostatic attraction body, channels for passing cooling medium therethrough and cover means for covering the exposed surfaces of the support body except a portion thereof over which the work is placed. This chuck can not only prevent impure matters from generating from the surfaces of the support body but also prevent damages due to heat.

16 Claims, 6 Drawing Figures



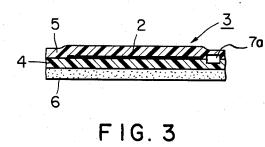








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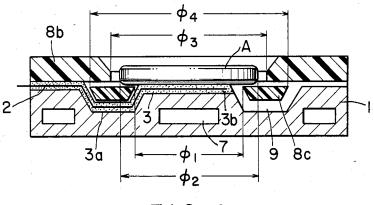


FIG.4

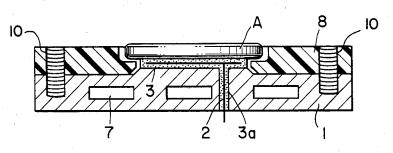


FIG. 5

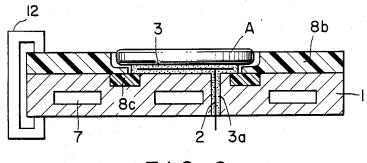


FIG. 6

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ELECTROSTATIC CHUCK

BACKGROUND OF THE INVENTION

This invention relates to an electrostatic chuck and more particularly to an improved electrostatic chuck for securing a work by electrostatic forces in a vacuum process apparatus such as a dry-etching apparatus.

In a vacuum microfabrication apparatus such as a dry-etching apparatus, a variety of means for securing a wafer have been used. In recent years electrostatic chucks are used for securing a specimen wafer by electrostatic forces.

Japanese Patent Laid-Open Publication No. 15 described below. 85828/1981 discloses an electrostatic chuck of a type which has a holding portion for holding a wafer. The holding portion is so formed that its size is almost the same as that of a wafer to be processed. The holding portion comprises a first insulator layer, a plurality of 20 static chuck and a specimen wafer placed thereon; electrodes provided upon the first insulator layer, and a second insulator layer provided upon the plurality of electrodes and over the first insulator layer. The other portion except the holding portion consists of a metal 25 support body such as a stainless steel member.

In operation, the specimen wafer is placed over the holding portion of the electrostatic chuck. When a high voltage is applied to the electrodes, the electrostatic attractive forces arise and attract and securely hold the specimen wafer in position. A vacuum process such as ³⁰ etching is done thereafter.

The above described electrostatic chuck can prevent wear and degradation of the second insulator layer contacting directly the wafer since the holding portion is entirely covered by the specimen wafer. However, ³⁵ though the insulator layer is protected from wearing, the upper surface of the metal support body is subjected to an etching process, with a result that the metallic material of the support body may disperse or scatter as 40 impurities.

In addition, although a high temperature during the etching process often has an adverse effect on the wafer, no consideration has been made to mitigate heat impacts regarding the electrostatic chuck.

SUMMARY OF THE INVENTION

It is an object of the present invention to provide an electrostatic chuck capable of holding a work by electrostatic forces without dispersing impure matters from 50 a metallic support body and of preventing damages due to high heat.

In one aspect of the present invention, the electrostatic chuck includes an electrostatic attraction body having an electrode and an insulator layer which buries 55 the electrode therein. The electrostatic attraction body attracts the work on its upper surface. The electrostatic chuck further includes below the electrostatic attraction body an electric conductive metal support body for tion body. The chuck has also channels for passing cooling medium such as cooling water either in the metal support body or in the electrostatic attraction body, an electric connection portion for supplying voltage across the electrode, and cover means placed at 65 least on the same side as the electrostatic attraction body with respect to the metal support body for covering the generation of impure matters from the exposed

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surfaces of the metal support body other than a portion on which the work is attracted.

In another aspect of the invention, the insulator layer is formed of thin films, the cover means is made of either a ceramic material or a heat resistant resin, and the metal support body is formed of a material with a sufficiently high thermal conductivity.

The present invention is further described with the aid of the accompanying drawings, which illustrate 10 preferred embodiments by way of an example only. The nature, utility and features of this invention will be more clearly apparent from the following detailed description with respect to the preferred embodiments when read in conjunction with the accompanying drawings briefly

BRIEF DESCRIPTION OF THE DRAWINGS

In the accompanying drawings:

FIG. 1 is an elevational sectional view of the electro-

FIG. 2 is a perspective view of the electrostatic chuck and the specimen wafer as shown in FIG. 1;

FIG. 3 is an enlarged elevational sectional view of the electrostatic attraction body shown in FIG. 1; and

FIGS. 4, 5 and 6, respectively, show a second, third and fourth embodiments in accordance with the present invention.

DETAILED DESCRIPTION OF THE PREFERRED EMBODIMENTS

Referring first to FIG. 1 in accordance with the first embodiment of the present invention, an improved electrostatic chuck with a specimen wafer A as a work placed thereon, includes an electrically conductive support body 1 at the bottom of the chuck. The support body 1 has, at its center, a round protrusion 1a with the thickness slightly greater than the rest of the body 1. The support body 1 is made of a material with a high conductivity such as copper or aluminum. To the upper surface of the protrusion 1a of the support body 1 is applied an electrostatic attraction body 3 in which a metallic electrode 2 is accommodated.

Referring next to FIGS. 2 and 3, the construction of the attraction body 3 will be explained in detail. The body 3 comprises an insulator layer and an adhesive 45 layer 6. The insulator layer has an insulator base film 4 and a insulator cover film 5. The insulator layer is made of an organic resin layer with the thickness of 10 to 100 µm, such as a polyimide layer or a polyester layer. To the insulator base film 4 made of polyimide or polyester is applied the electrode 2 made of, for example, copper film with the thickness of 10 to 50 µm. After the electrode 2 is formed in a preselected form, the insulator cover film 5 made of polyimide or polyester is applied to the electrode 2, placing the electrode 2 between the insulator cover film 5 and the insulator base film 4. Further, on the bottom of the insulator base film 4 is provided the adhesive layer 6.

The electrode 2 may be made of a metallic film with supporting the lower surface of the electrostatic attrac- 60. the thickness of less than 2 μ m, formed on the insulator base film 4 or the insulator cover film 5 by means of vacuum evaporation or sputtering.

> In this embodiment, for example, the thicknesses of both the insulator base film 4 and the insulator cover film 5 are 50 μ m, respectively, the thickness of the copper-made electrode 2 is 18 μ m, the adhesive layer 6 is 40 μ m, and the entire thickness of the electrostatic attraction body 3 amounts to 158 μ m. It is desirable that

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the body 3 is formed as thin as possible in order to increase heat transmission efficiency. Both the electrostatic attraction body 3 and the specimen wafer A have circular shapes, respectively. However, the electrostatic attraction body 3 has an attracting surface slightly 5 smaller than the surface, to be attracted, of the specimen wafer A. A portion of the periphery of the electrostatic attraction body 3 is so projected from its circular main body 3b as to form an electric connection portion 3a for connecting the electrode 2 with an external power sup- 10 ply, not shown.

Referring back to FIG. 1, through the support body 1, there are provided a plurality of channels 7 for passing cooling medium therethrough in order to cool the wafer A. Such channels may be formed in the electro- 15 regard to the dimensions of the elements are: static attraction body 3 (shown at 7a in FIG. 3). The electrostatic chuck according to the present invention is further provided with a cover plate 8 applied onto the support body 1 by means of an adhesive The cover plate 8 has a round aperture 8a at its center for placing the 20 wafer A therein. The cover plate 8 can cover the exposed surfaces except the surface of the protrusion 1a on which the wafer A is placed and is formed of a ceramic material such as carbon, quartz, alumina, silicon carbide (SiC), or silicon nitride (SiN), etc. The cover 25 plate 8 may be formed of a heat-resistant synthetic resin such as polyimide or fluoreoresin, etc. Further, the cover plate 8 may be fixed to the support body 1 by means of screws (see element 10 in FIG. 5). In addition, the cover plate 8 may be simply placed or clamped upon 30 the support body 1 by means of a clamping member provided on the periphery of the cover means (See element 12 in FIG. 6).

In accordance with the above-described first embodiment, in operation, the specimen wafer A is placed upon 35 the electrostatic attraction body 3, and thereafter a DC voltage is applied to the electrode 2. The wafer A is thus attracted by means of electrostatic forces and is secured on the electrostatic attraction body 3. The electrostatic chuck described above is placed in a vacuum 40 chamber, and a vacuum process such as etching operation, etc. is carried out for the specimen wafer A. In the meantime, cooling water is provided through the channels 7 during the processing.

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It is to be understood that loading and unloading of 45 the speciment wafer A on the electrosatic chuck are done by a loader mechanism, not shown, which is provided through the support body 1 and which is capable of vertically lifting and lowering the wafer A through the support body 1. The electrostatic attraction body 3 50 and the support body 1 are provided with apertures (not shown) to permit the vertical movements of the lifting mechanism, respectively.

Accordingly, with the aforementioned construction of the electrostatic chuck in accordance with this inven- 55 tion, since the exposed surface of the support body 1 except the surface of protrusion la on which the wafer A is placed is covered with the cover plate 8, the material of the support body is no longer directly hit by ion beams nor scattered during an etching process. In addi- 60 tion, no impure materials are generated in the vacuum processing chamber.

Moreover, with the aid of cooling water passing through the channels in the support body 1, the support body 1 is cooled off desirably and consequently the 65 specimen wafer A does not suffer damage due to heat.

In FIG. 4, an electrostatic chuck according to a second embodiment of the current invention is shown. In the embodiment, an annular groove 9 is formed around the entire periphery of the central protrusion 1a of the support body 1. As is the case with respect to the first embodiment, an electrostatic attraction body 3 is fixed to the upper surface of a round protrusion la formed by digging an annular groove 9. An electric connection portion 3a is projected from the main body 3b of the attraction body 3 and extended across the groove 9.

Over the whole upper surfaces of the support body 1 and the groove 9, with the exception of the circular protrusion upon which the specimen wafer A is to be placed, a cover plate 8b and a cover ring 8c are placed, respectively.

In this embodiment, the preferred relationships with

 $\phi_1 < \phi_2$

 $\phi_2 < \phi_3$

φ3<φ4

where

 ϕ_1 : the internal diameter of the cover ring 8c placed in the groove 9,

 ϕ_2 : the diameter of the specimen wafer A,

 ϕ_3 : the internal diameter of the cover plate 8b, and ϕ_4 : the external diameter of the cover plate 8b.

It is apparent that in accordance with the second embodiment it is also possible, by means of the two pieces of the cover members 8b, 8c, to prevent the material of the support body 1 from dispersing or scattering, by keeping the ion beam impacts away from the support body 1. The embodiment also ensures satisfactory cooling effects by the cooling water passing through the channels 7.

Referring to FIG. 5 illustrating the third embodiment of the current invention, an electrostatic chuck includes an electrostatic attraction body 3 which has an electric connection portion 3a extending downward through the support body 1 for an electrical connection. This structure enables the electrostatic chuck to be connected to a power source directly below the support body 3. This construction also ensures to prevent ion beam from attacking the upper surface of the support body 1.

Referring next to FIG. 6, the electrostatic chuck in accordance with the fourth embodiment of the invention includes a cover ring 8c provided immediately below the adjoining portion of a cover plate 8b and the electrostatic attraction body 3. The provision of the cover members 8b, 8c further ensures to prevent ion beam from hitting the upper surface of the support body 1. Naturally, the fourth embodiment also ensures the electrostatic chuck to be connected to a power source directly below the support body 1, as is the case with the third embodiment described above.

Preferably, if the support body 1 is made of aluminum, an anodic oxidation process should be carried out on the surface of the support body 1. In this case, an anodic oxidation layer forms cover means instead of the cover members 8b, 8c.

As thus has been described it should be clear that in accordance with the current invention, it is possible to prevent the generation of the impurities by the provision of the cover means and to prevent the wafer from suffering damages due to heat by the provison of the cooling means.

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